

4.5Ω、300MHz 带宽、双通道、单刀双掷 (SPDT) 模拟开关

UM4258Q QFN10 1.80×1.40

描述

UM4258Q是一款低电压、低导通电阻、双通道单刀双掷（SPDT）模拟开关，单工作电源电压范围为+1.8V 至 +5.5V。该器件专为USB1.1/2.0接口和音频开关应用而设计。

UM4258Q具有两路最大导通电阻为4.5Ω的单刀双掷（SPDT）开关，通道间平坦度为1.2Ω，匹配度为0.3Ω。在+2.7V电压下，该器件支持先断后通切换模式（断开与闭合间隔1ns），其 $t_{ON}<80ns$ ， $t_{OFF}<40ns$ 。数字逻辑输入为 +1.8V逻辑输入，兼容 +2.7V 至 +3.6V 电源。

UM4258Q 采用 1.80mm×1.40mm QFN10封装，大大减少了所需PCB面积。

应用

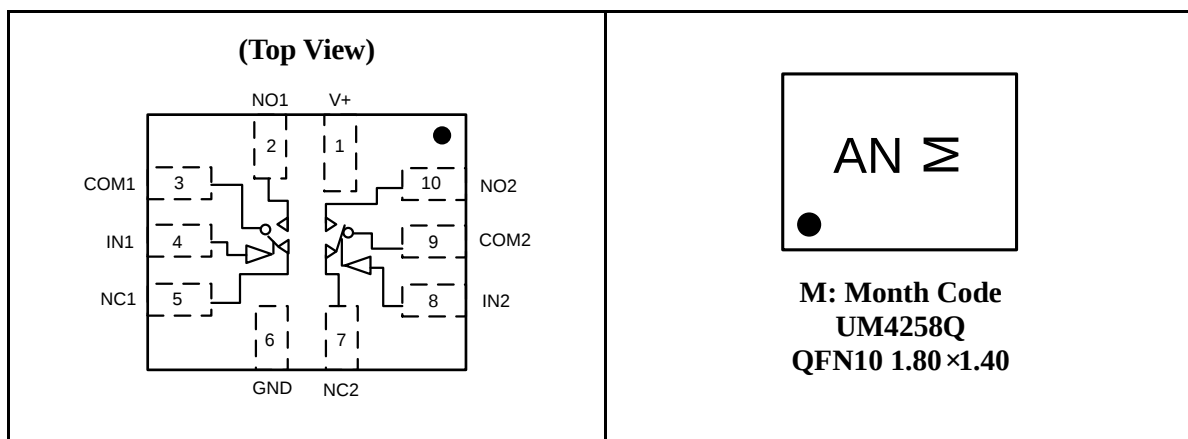
- USB 1.1/2.0 信号切换电路
- 电池供电设备
- 音频/视频信号路由
- 耳机切换
- 低电压数据采集系统
- 采样和保持电路
- 手机
- 掌上电脑

特性

- 最大 2ns 差分偏移
- -3dB 带宽：300MHz
- 低至 15pF 的通道电容
- +1.8V 至 +5.5V 单电源运行
- 4.5Ω 导通电阻（最大值）开关
- 0.3Ω (最大值) 通道间导通电阻匹配 (+3.0V 电源)
- 1.2Ω (最大值) 平坦度 (+3.0V 电源)
- 轨对轨信号处理
- 高隔离度：-55dB (10MHz)
- 低串扰：-80dB (10MHz)
- 低失真：0.03%
- 兼容+1.8V CMOS 逻辑
- +25℃ 时的漏电流< 0.5nA

引脚配置

顶部视图



Pin Description

Pin Number	Name	Function
7	NC2	Analog Switch 2-Normally Closed Terminal
8	IN2	Analog Switch 2-Digital Control Input
9	COM2	Analog Switch 2-Common Terminal
10	NO2	Analog Switch 2-Normally Open Terminal
6	GND	Ground Connection
1	V ₊	Positive Supply Voltage
5	NC1	Analog Switch 1-Normally Closed Terminal
4	IN1	Analog Switch 1-Digital Control Input
3	COM1	Analog Switch 1-Common Terminal
2	NO1	Analog Switch 1-Normally Open Terminal

Ordering Information

Part Number	Packaging Type	Marking Code	Shipping Qty
UM4258Q	QFN10 1.80×1.40	AN	3000pcs/7 Inch Tape & Reel

Function Table

IN ₋	NO ₋	NC ₋
0	OFF	ON
1	ON	OFF

Absolute Maximum Ratings

Symbol	Parameter		Limit	Unit
V ₊	Supply Voltage		-0.3 to +6.0	V
V _S	DC Switch Voltage (Note 1)		-0.3 to (V ₊ +0.3)	
IN ₋	DC IN Voltage		-0.3 to +6.0	
I _O	Continuous Current (COM ₋ , NO ₋ , NC ₋)		±100	mA
I _P	Peak Current (Pulsed at 1ms, 10% Duty Cycle)		±200	
T _O	Operating Temperature Range		-40 to +85	℃
T _J	Junction Temperature		+150	
T _{STG}	Storage Temperature Range		-65 to +150	
T _L	Junction Lead Temperature (Soldering, 10 Seconds)		+300	
T _{Bump}	Bump Temperature (Soldering)	Infrared (15s)	+220	
		Vapor Phase (60s)	+215	
P _D	Continuous Power Dissipation @ +70 ℃		909	mW
ESD	ESD Method 3015.7		>2000	V

Note 1: Signals on COM₋, NO₋, or NC₋ exceeding V₊ or GND are clamped by internal diodes.
Limit forward-diode current to maximum current rating.

DC Electrical Characteristics (Single +3V Supply)

($V_+ = +2.7V$ to $+3.6V$, $V_{IH} = +1.4V$, $V_{IL} = +0.5V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_+ = +3.0V$, $T_A = +25^\circ C$) (Note 2, 3)

Symbol	Parameter	Test Conditions	Temp	Limits (-40 °C to 85 °C)			Unit
				Min	Typ	Max	
DC Electrical Characteristics							
$V_{COM_}$ $V_{NO_}$ $V_{NC_}$	Analog Signal Range		Full	0		V+	V
V+	Power Supply Range		Full	1.8		5.5	V
I+	Supply Current	V+=+5.5V, VIN_=0V or V+	Full			1	μA
ICOM_(ON)	COM_On Leakage Current (Note 7)	V+=+3.6V, VCOM_=0.3V, 3.3V; VNO_ or VNC_=0.3V, 3.3V, or Floating	Room Full	-1 -2	+0.01	+1 +2	nA
IOFF	OFF State Leakage Current (Note 7)	V+=+3.6V, VCOM_=0.3V, 3.3V; VNO_ or VNC_=3.3V, 0.3V	Room Full	-0.5 -1	+0.01	+0.5 +1	nA
VIH	Input High Voltage		Full	1.4			V
VIL	Input Low Voltage		Full			0.5	V
IIN	Input Leakage Current	V+=+3.6V, VIN_=0 or 5.5V	Full	-100		+100	nA
RON	On-Resistance (Note 4)	V+=+2.7V, ICOM_=10mA; VNO_ or VNC_=1.5V	Room		3.0	4.5	Ω
			Full			5	
ΔRON	On Resistance Match Between Channels (Note 4, 5)	V+=+2.7V, ICOM_=10mA; VNO_ or VNC_=1.5V	Room		0.1	0.3	Ω
			Full			0.4	
RFLAT	On Resistance Flatness (Note 6)	V+=+2.7V, ICOM_=10mA; VNO_ or VNC_=1.0V, 1.5V, 2.0V	Room		0.6	1.2	Ω
			Full			1.5	

AC Electrical Characteristics (Single +3V Supply)

($V_+ = +2.7V$ to $+3.6V$, $V_{IH} = +1.4V$, $V_{IL} = +0.5V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_+ = +3.0V$, $T_A = +25^\circ C$) (Note 2, 3)

Symbol	Parameter	Test Conditions	Temp	Limits (-40 °C to 85 °C)			Unit
				Min	Typ	Max	
AC Electrical Characteristics							
t _{ON}	Turn-On Time	V _{NO_} , V _{NC_} =1.5V; R _L =300Ω, C _L =35pF, Figure 1; V _{IH} =1.5V, V _{IL} =0V	Room Full		40	80 100	ns
t _{OFF}	Turn-Off Time	V _{NO_} , V _{NC_} =1.5V; R _L =300Ω, C _L =35pF, Figure 1; V _{IH} =1.5V, V _{IL} =0V	Room Full		20	40 50	ns
t _{BBM}	Break Before Make Time (Note 7)	V _{NO_} , V _{NC_} =1.5V; R _L =300Ω, C _L =35pF, Figure 2	Room Full	1	8		ns
t _{SKEW}	Skew (Note 7)	R _S =39Ω, C _L =50pF, Figure 3	Full		0.15	2	ns
Q _{INJ}	Charge Injection	C _L =1.0nF, Figure 4 V _{GEN} =1.5V, R _{GEN} =0Ω	Room		5		pC
V _{ISO}	Off Isolation	f=10MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5	Room		-55		dB
		f=1MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5			-80		
V _{CT}	Crosstalk (Note 8)	f=10MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5	Room		-80		dB
		f=1MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5			-110		
BW	-3dB Bandwidth	Signal=0dBm, R _L =50Ω, C _L =5pF, Figure 5	Room		300		MHz
THD	Total Harmonic Distortion	R _L =600Ω, V _{COM_} =2V _{P-P}	Room		0.03		%
Capacitance							
C _{NO_(OFF)} C _{NC_(OFF)}	NO_, NC_ Off Capacitance	f=1MHz, Figure 6	Room		9		pF
C _(ON)	Switch On Capacitance	f=1MHz, Figure 6	Room		15		pF

DC Electrical Characteristics (Single +5V Supply)

($V_+ = +4.2V$ to $+5.5V$, $V_{IH} = +2.0V$, $V_{IL} = +0.8V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_+ = +5.0V$, $T_A = +25^\circ C$) (Note 2, 3)

Symbol	Parameter	Test Conditions	Temp	Limits (−40 °C to 85 °C)			Unit
				Min	Typ	Max	
DC Electrical Characteristics							
$V_{COM_}$ $V_{NO_}$ $V_{NC_}$	Analog Signal Range		Full	0		V+	V
V+	Power Supply Range		Full	1.8		5.5	V
I+	Supply Current	V+=+5.5V, VIN_=0V or V+	Full			1	μA
ICOM_(ON)	COM_On Leakage Current (Note 7)	V+=+5.5V, VCOM_=1.0V, 4.5V; VNO_ or VNC_=1.0V, 4.5V, or Floating	Room Full	-1 -2	+0.01	+1 +2	nA
IOFF	OFF State Leakage Current (Note 7)	V+=+5.5V, VCOM_=1.0V, 4.5V; VNO_ or VNC_=1.0V, 4.5V	Room Full	-0.5 -1	+0.01	+0.5 +1	nA
VIH	Input High Voltage		Full	2.0			V
VIL	Input Low Voltage		Full			0.8	V
IIN	Input Leakage Current	V+=+5.5V, VIN_=0 or V+	Full	-100		+100	nA
RON	On-Resistance (Note 4)	V+=+4.2V, ICOM_=10mA; VNO_ or VNC_=3.5V	Room		1.7	3	Ω
			Full			3.5	
ΔRON	On Resistance Match Between Channels (Note 4, 5)	V+=+4.2V, ICOM_=10mA; VNO_ or VNC_=3.5V	Room		0.1	0.3	Ω
			Full			0.4	
RFLAT	On Resistance Flatness (Note 6)	V+=+4.2V, ICOM_=10mA; VNO_ or VNC_=1.0V, 2.0V, 3.5V	Room		0.4	1.2	Ω
			Full			1.5	

AC Electrical Characteristics (Single +5V Supply)

($V_+ = +4.2V$ to $+5.5V$, $V_{IH} = +2.0V$, $V_{IL} = +0.8V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_+ = +5.0V$, $T_A = +25^\circ C$) (Note 2, 3)

Symbol	Parameter	Test Conditions	Temp	Limits (−40 °C to 85 °C)			Unit
				Min	Typ	Max	
AC Electrical Characteristics							
t _{ON}	Turn-On Time	V _{NO_} , V _{NC_} =3.0V; R _L =300Ω, C _L =35pF, Figure 1;	Room Full		30	80 100	ns
t _{OFF}	Turn-Off Time	V _{NO_} , V _{NC_} =3.0V; R _L =300Ω, C _L =35pF, Figure 1;	Room Full		20	40 50	ns
t _{BBM}	Break Before Make Time (Note 7)	V _{NO_} , V _{NC_} =3.0V; R _L =300Ω, C _L =35pF, Figure 2	Room Full	1	8		ns
t _{SKEW}	Skew (Note 7)	R _S =39Ω, C _L =50pF, Figure 3	Full		0.15	2	ns
Q _{INJ}	Charge Injection	C _L =1.0nF, Figure 4 V _{GEN} =1.5V, R _{GEN} =0Ω	Room		9		pC
V _{ISO}	Off Isolation	f=10MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5	Room		-55		dB
		f=1MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5			-80		
V _{CT}	Crosstalk (Note 8)	f=10MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5	Room		-80		dB
		f=1MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5			-110		
BW	-3dB Bandwidth	Signal=0dBm, R _L =50Ω, C _L =5pF, Figure 5	Room		300		MHz
THD	Total Harmonic Distortion	R _L =600Ω, V _{COM_} =2V _{P-P}	Room		0.03		%
Capacitance							
C _{NO_(OFF)} C _{NC_(OFF)}	NO_, NC_ Off Capacitance	f=1MHz, Figure 6	Room		9		pF
C _(ON)	Switch On Capacitance	f=1MHz, Figure 6	Room		15		pF

Note 2: The parts are 100% tested at $+25^\circ C$ only, and guaranteed by design over the specified temperature range.

Note 3: The algebraic convention used in this data sheet is where the most negative value is a minimum and the most positive value is a maximum.

Note 4: Guaranteed by design.

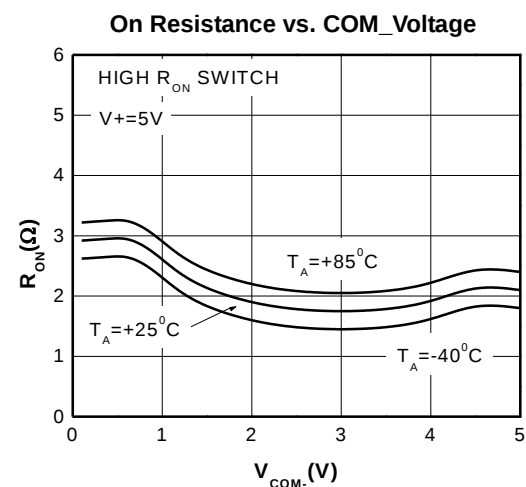
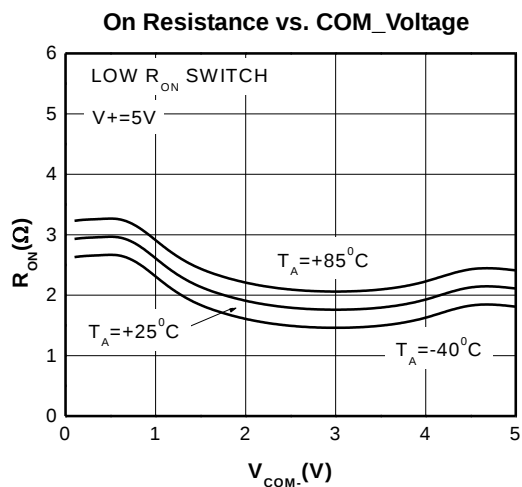
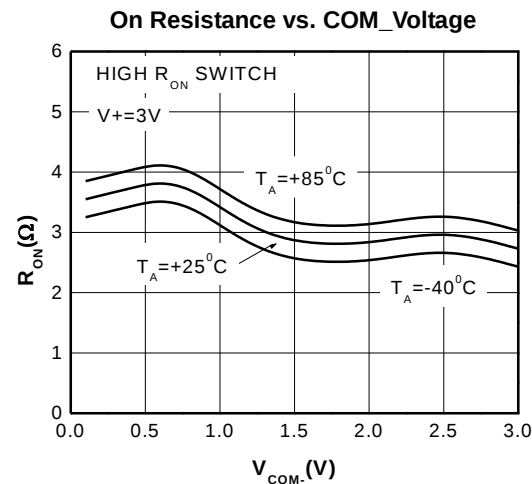
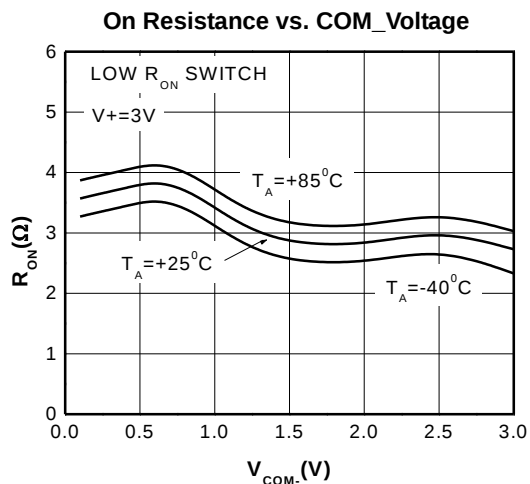
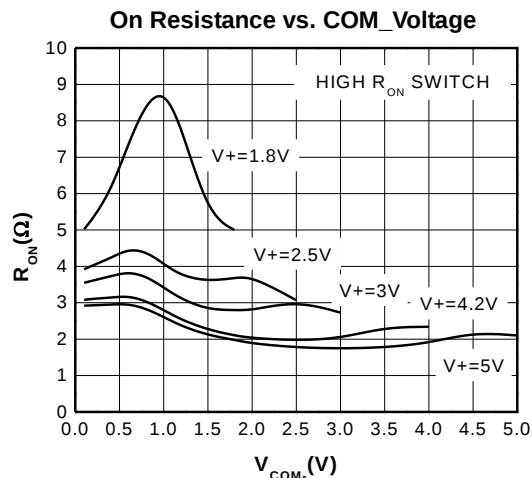
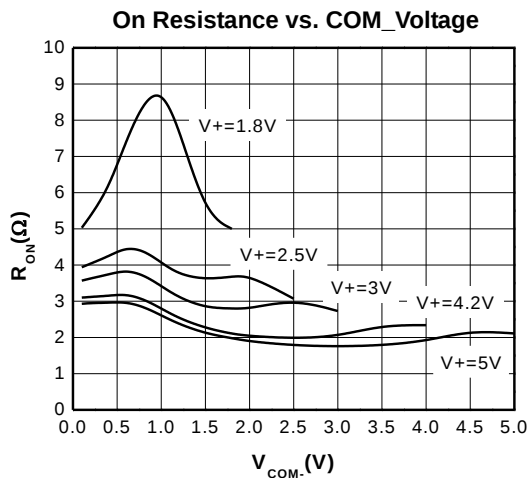
Note 5: $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$.

Note 6: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

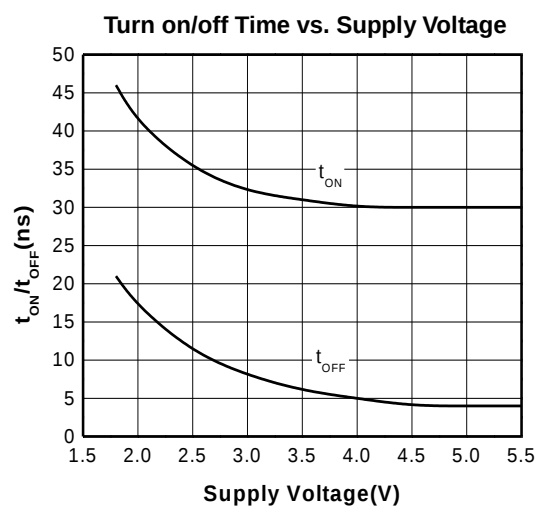
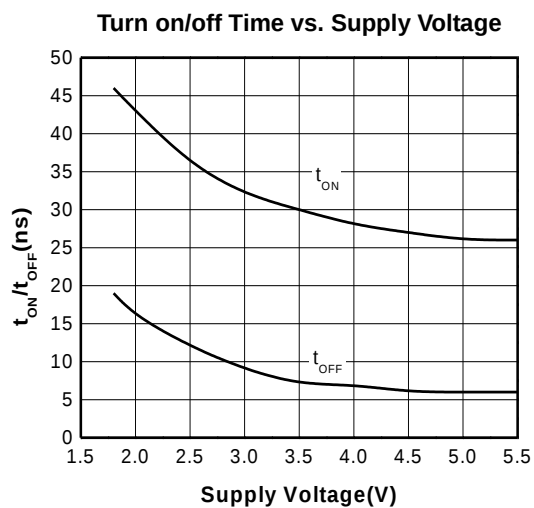
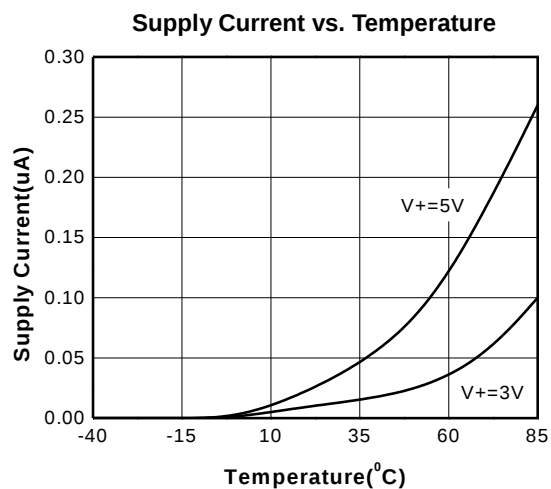
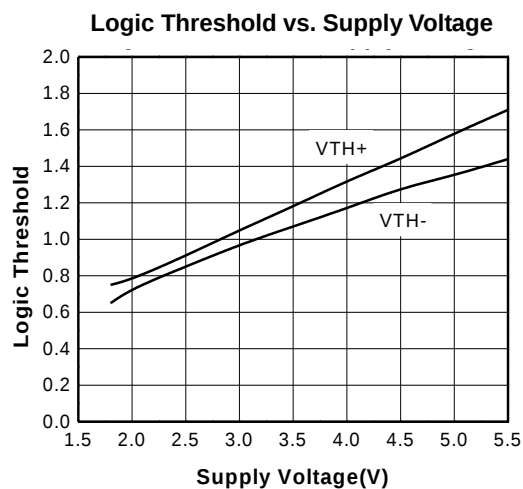
Note 7: Guaranteed by design.

Note 8: Between any two switches.

Typical Operating Characteristics

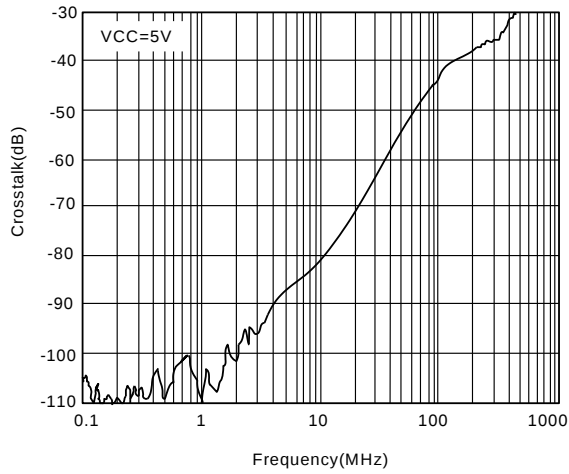


Typical Operating Characteristics (Continued)

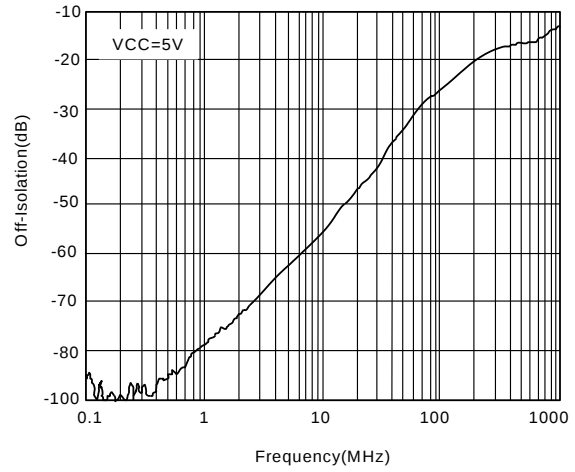


Typical Operating Characteristics (Continued)

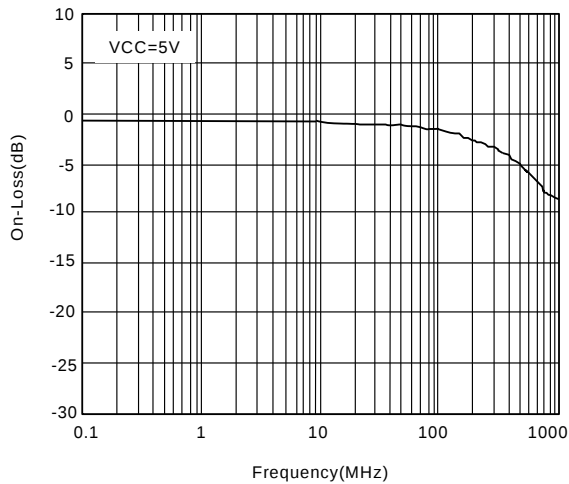
Crosstalk vs. Frequency



Off-Isolation vs. Frequency



On-Loss vs. Frequency



Detailed Description

The UM4258Q high-speed, low-voltage, low on-resistance (R_{ON}), dual SPDT analog switch operates from a single +1.8V to +5.5V supply. The switch features break-before-make switching operation and fast switching speeds ($t_{ON}=80\text{ns}$ (max), $t_{OFF}=40\text{ns}$ (max)).

The switch has low 15pF on-channel capacitance, which allows for 12Mbps switching of the data signals for USB 1.0/1.1 applications. The UM4258Q is designed to switch D₊ and D₋ USB signals with a guaranteed skew of less than 2ns (see Figure 4) as measured from 50% of the input signal to 50% of the output signal.

Applications Information

Digital Control Inputs

The UM4258Q logic inputs accept up to +5.5V regardless of supply voltage. For example, with a +3.3V supply, IN₋ can be driven low to GND and high to +5.5V allowing for mixing of logic levels in a system. Driving the control logic inputs rail-to-rail minimizes power consumption. For a +3V supply voltage, the logic thresholds are 0.5V (low) and 1.4V (high); for a +5V supply voltage, the logic thresholds are 0.8V (low) and 2.0V (high).

Analog Signal Levels

The on-resistance of the UM4258Q changes very little for analog input signals across the entire supply voltage range (see the Typical Operating Characteristics). The switches are bidirectional, so the NO₋, NC₋, and COM₋ pins can be either inputs or outputs.

Power-Supply Sequencing and Over-Voltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Always apply V₊ before applying analog signals, especially if the analog signal is not current-limited.

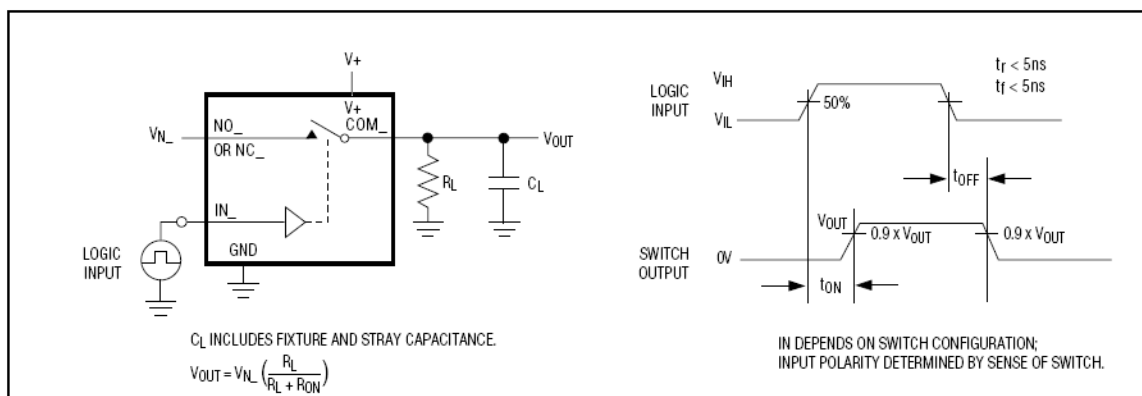


Figure 1. Switching Time

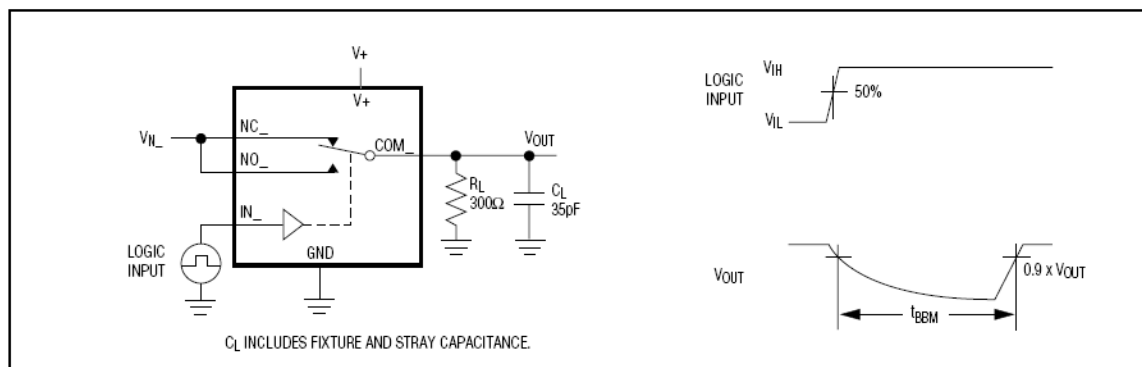


Figure 2. Break-Before-Make Interval

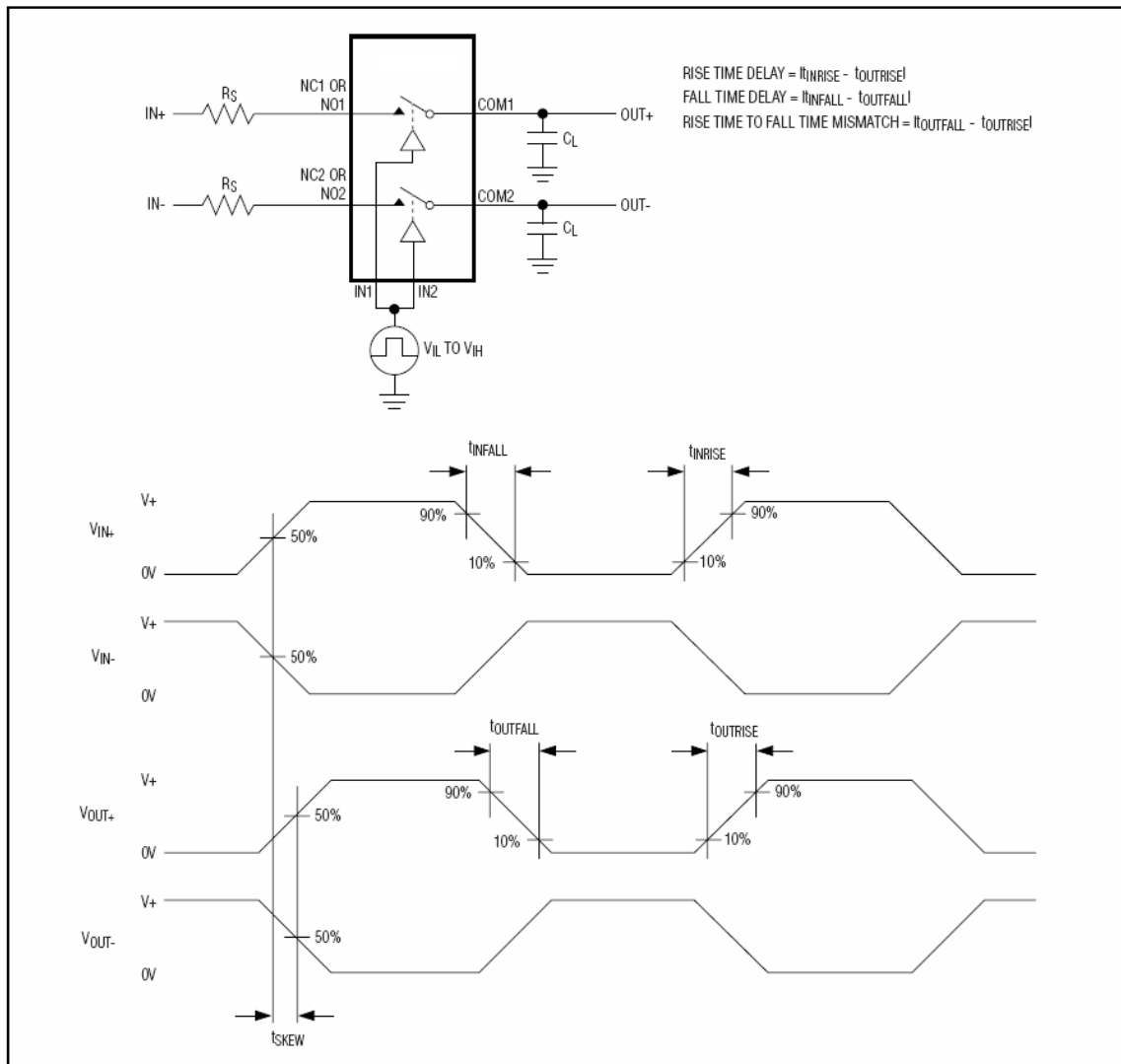


Figure 3. Output Signal Skew

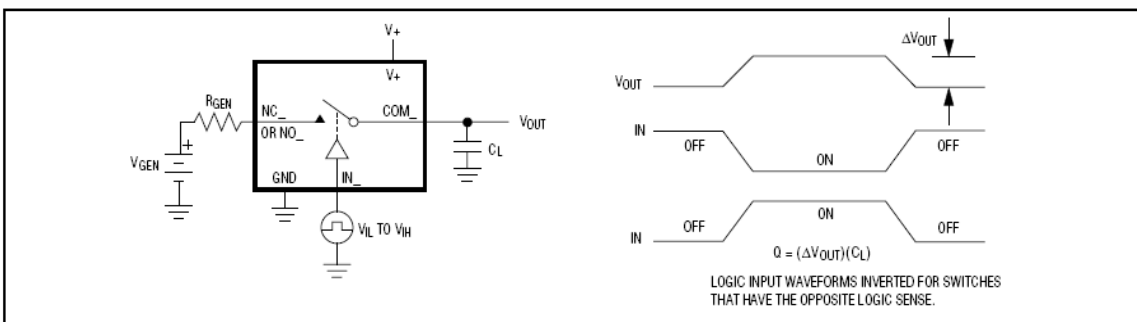


Figure 4. Charge Injection

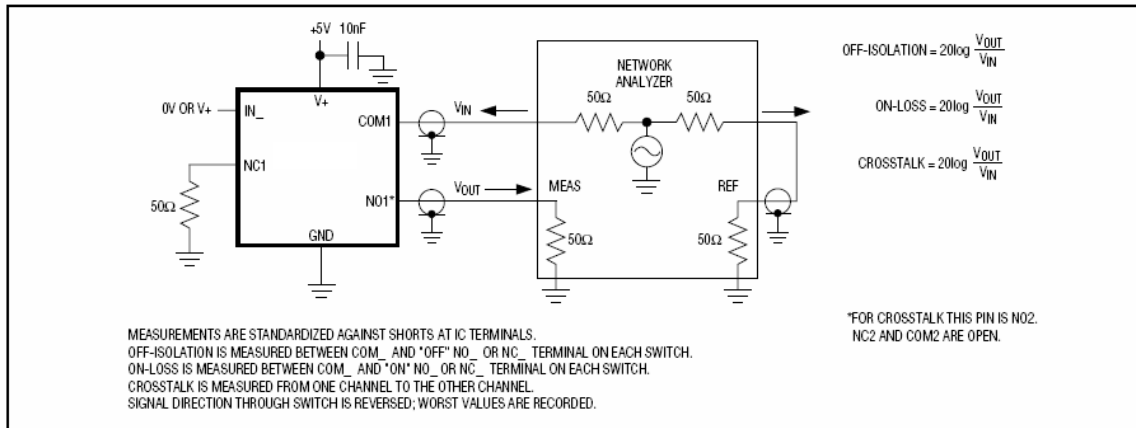


Figure 5. On-Loss, Off-Isolation, and Crosstalk

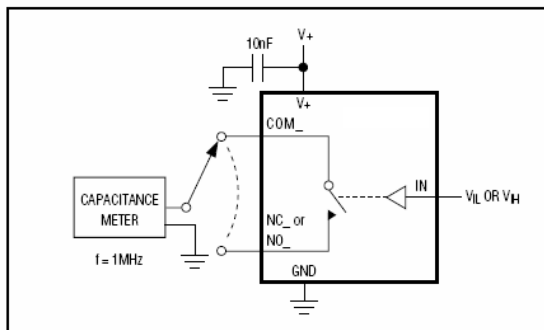
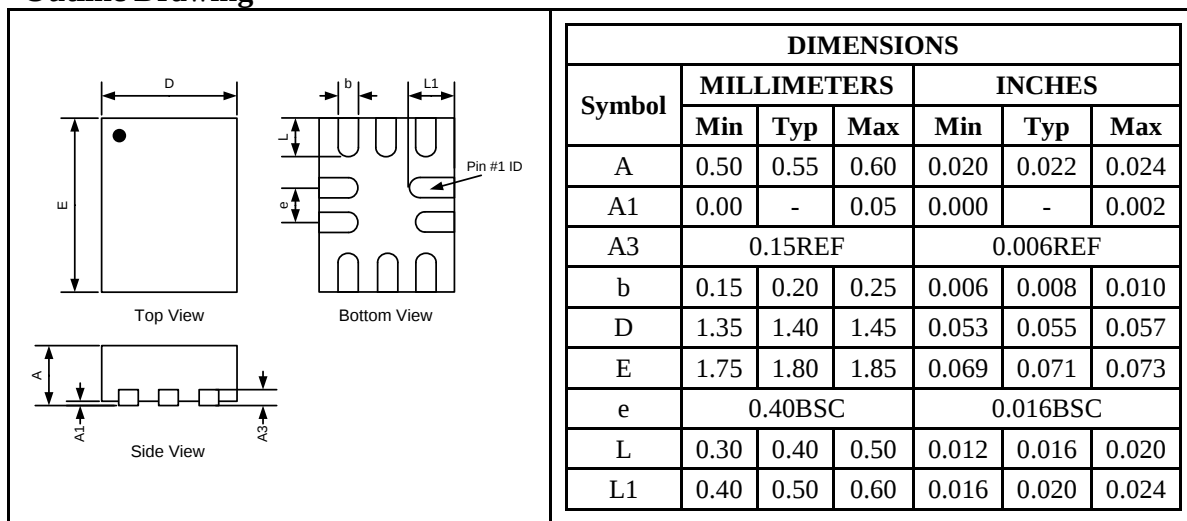


Figure 6. Channel Off/On-Capacitance

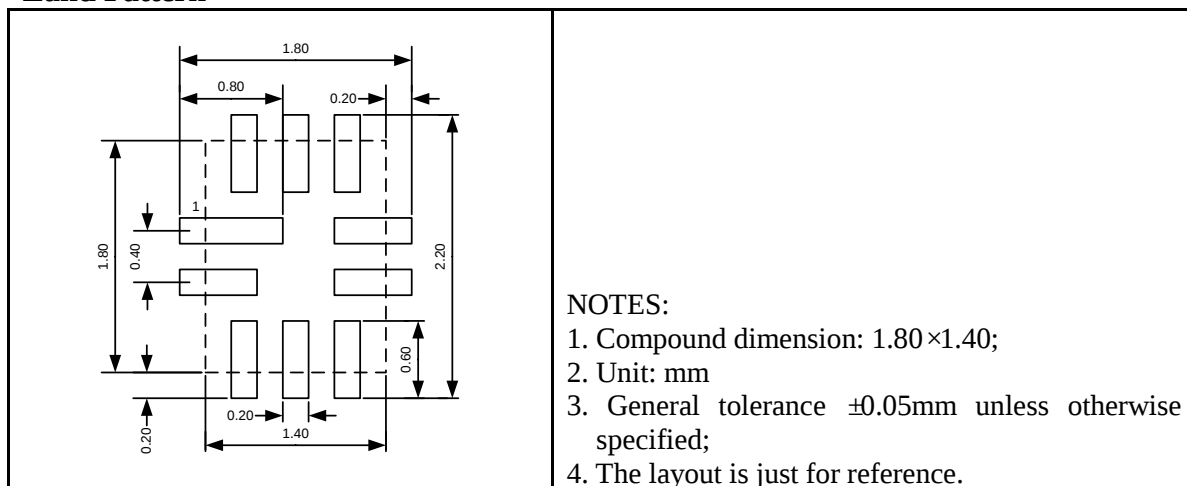
Package Information

UM4258Q: QFN10 1.80×1.40

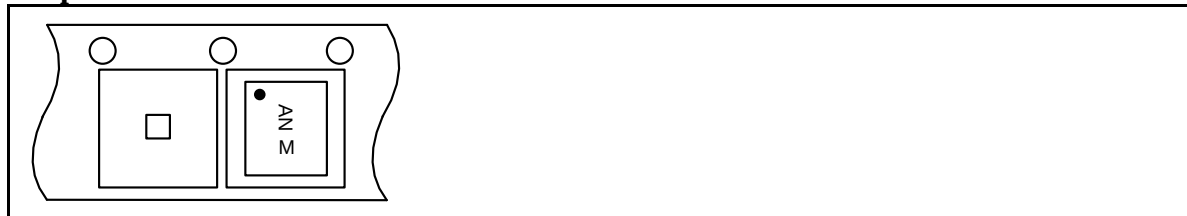
Outline Drawing



Land Pattern



Tape and Reel Orientation



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